

MFC8000 thru MFC8002

HIGH-FREQUENCY CIRCUITS

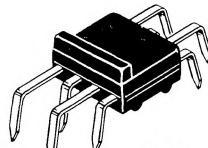
MONOLITHIC DUAL STEREO AMPLIFIER

. . . designed for the input stage of stereo power amplifiers.

- Excellent Channel Separation – 60 dB minimum
- High Gain – $hFE = 75$ minimum
- Satisfies Both Channel Requirements with One Compact Package
- Selection of Breakdown Voltages to Meet the Particular Applications

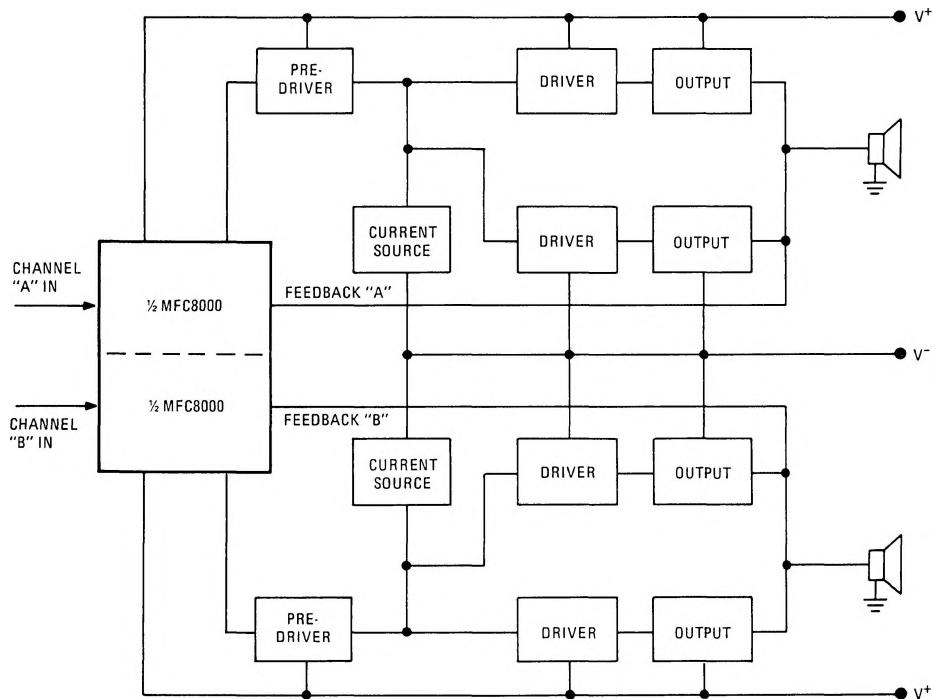
DUAL DIFFERENTIAL AMPLIFIER (Stereo Input Amplifier)

SILICON MONOLITHIC
CONSUMER CIRCUIT



CASE 644A
PLASTIC PACKAGE

TYPICAL APPLICATION



MFC8000, MFC8001, MFC8002 (continued)

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Maximum Supply Voltage – MFC8000 MFC8001 MFC8002	V ⁺	40 50 60	Vdc
Power Dissipation (Package Limitation) (Soldered on a circuit board) Derate above $T_A = 25^\circ\text{C}$	P _D	1.0 10	Watt mW/ $^\circ\text{C}$
Operating Temperature Range	T _A	-10 to +75	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Collector-Emitter Breakdown Voltage (I _C = 1.0 mAdc, I _B = 0) MFC8000 MFC8001 MFC8002	V _{CEO}	40 50 60	— — —	— — —	Vdc
DC Current Gain (V _{CE} = 20 Vdc, I _C = 1.0 mAdc)	h _{FE}	75	100	—	—
Base Differential Voltage (V _{CE} = 20 Vdc, I _C = 1.0 mAdc)	ΔV _{BE3} - ΔV _{BE2} ΔV _{BE8} - ΔV _{BE7}	—	—	15	mVdc
Base Differential Current (V _{CE} = 20 Vdc, I _C = 1.0 mAdc)	ΔI _{B3} - ΔI _{B2} ΔI _{B8} - ΔI _{B7}	—	—	1.0	μAdc
Channel Separation (Pins 2,3,8 grounded, signal at pin 7, e _{out} 1 at pin 6, e _{out} 2 at pin 4)	e _{out} 1 e _{out} 2	60	—	—	dB

CIRCUIT SCHEMATIC

